

DATASHEET

ITR8307/L24

Features

- Fast response time
- High sensitivity
- Cut-Off visible wavelength
- Thin
- Compact
- Pb free
- The product itself will remain within RoHS compliant version
- Compliance with EU REACH
- Compliance Halogen Free(Br < 900ppm, Cl < 900ppm, Br+Cl < 1500ppm)



Description

ITR8307/L24 is a light reflection switch which includes a GaAs IR-LED transmitter and a NPN photo-transistor with a high photosensitive receiver for short distance, operating in the infrared range. Both components are mounted side- by- side in a plastic package.

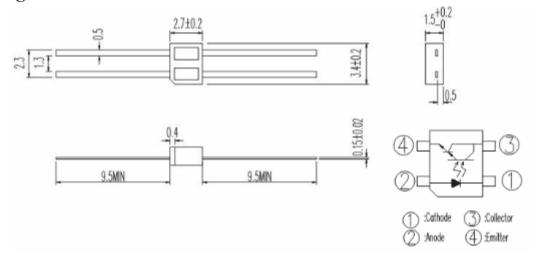
Applications

- Camera
- VCR
- Floppy disk driver
- Cassette type recorder
- Various microcomputer control equipment

Device Selection Guide

Device No.	Chip Material
IR	GaAs
PT	Silicon

Package Dimensions



Notes: 1.All dimensions are in millimeters

2. Tolerances unless dimensions ±0.25mm

Absolute Maximum Ratings (Ta=25°C)

Parameter	EVE	Symbol	Rating	Unit
	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
Input	Reverse Voltage	V_R	6	V
	Forward Current	I_{F}	50	mA
	Peak Forward Current (*1) Pulse width ≤100µs, Duty cycle=1%	I_{FP}	1	A
	Collector Power Dissipation	$P_{\rm C}$	100	mW
Output	Collector Current	$I_{\rm C}$	20	mA
	Collector-Emitter Voltage	B V _{CEO}	35	V
	Emitter-Collector Voltage	B V _{ECO}	6	V
Operating	Temperature	Topr	-25~+85	-25~+70
Storage Temperature		Tstg	-30~+90	-30~+80
Lead Solo	lering Temperature (*2)	Tsol	260	260

Notes: (± 1) tw=100 µsec., T=10 msec. (± 2) t=5 Sec



Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Condition
Input	Forward Voltage	$V_{\scriptscriptstyle F}$		1.2	1.4	V	I _F =20mA
	Reverse Current	I_{R}			10	μΑ	V _R =6V
	Peak Wavelength	$\lambda_{ m P}$		940		nm	
Output	Dark Current	I _{CEO}			1	nA	V _{CE} =10V Ee=1mW/cm ²
Transfer Characteristics	Light Current	I _{C(ON)}	0.5	3.0	15.0	mA	V _{CE} =2V, I _F =4mA
	Leakage Current	I _{LEAK}	-	-	5	μΑ	V _{CE} =2V, I _F =4mA
	Rise time	$t_{\rm r}$	-	80	400	μs	V _{CE} =2V I _C =10mA
	Fall time	t_{f}	-	70	400	μs	$R_L=100\Omega, \\ d=1mm$

Rank

 $Conditions : I_F\!\!=\!\!4mA \quad V_{CE}\!\!=\!\!2V$

Unit: mA

Bin number	Min	Max
В	0.50	1.10
C	0.90	1.90
D	1.45	3.20
Е	2.45	5.40
F	4.05	8.90
G	6.30	15.0

Typical Electrical/Optical/Characteristics Curves for IR

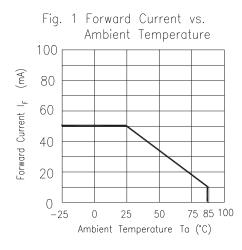


Fig. 3 Peak Emission Wavelength vs.
Ambient Temperature

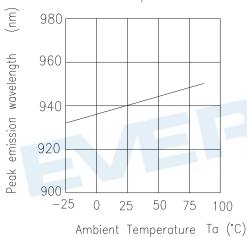


Fig. 5 Forward Voltage vs.

Ambient Temperature

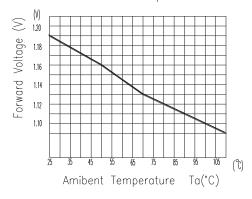


Fig. 2 Spectral Distribution

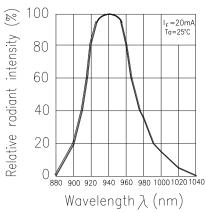


Fig. 4 Forward Current vs. Forward Voltage

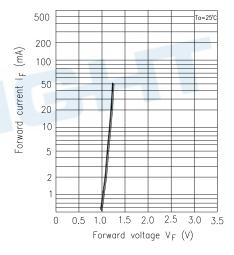
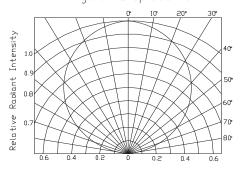


Fig. 6 Relative Radiant Intensity vs.
Angular Displacement



Typical Electrical/Optical/Characteristics Curves for PT

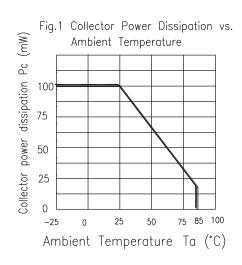


Fig. 3 Relative Collector Current vs.
Ambient Temperature

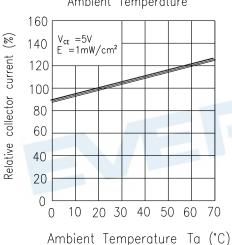


Fig.5 Spectral Sensitivity

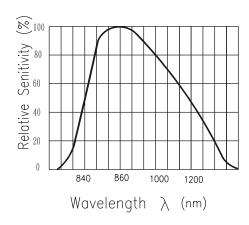


Fig.2 Collector Dark Current vs.
Ambient Temperature

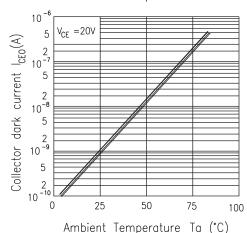


Fig.4 Collector Current vs.

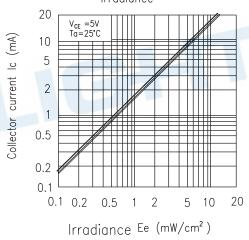
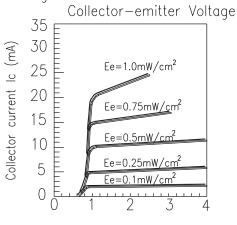


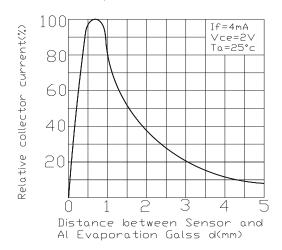
Fig.6 Collector Current vs.



Collector-emitter Voltage V cE (V)

Typical Electrical/Optical/Characteristics Curves for ITR

Fig.7 Relative Collector Current vs.
Distance between Sensor and
Al Evaporation Galss



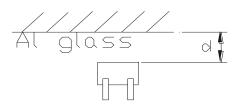
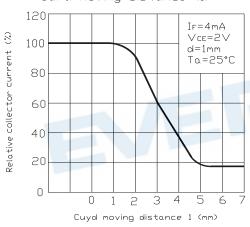


Fig.8 Relative Collector Current vs. Card Moving Distance (1)



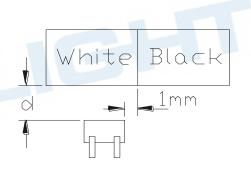
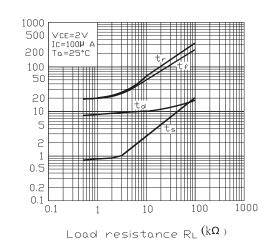
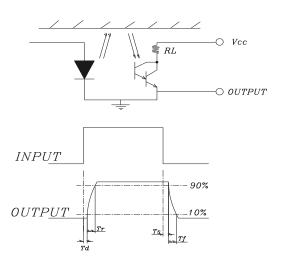


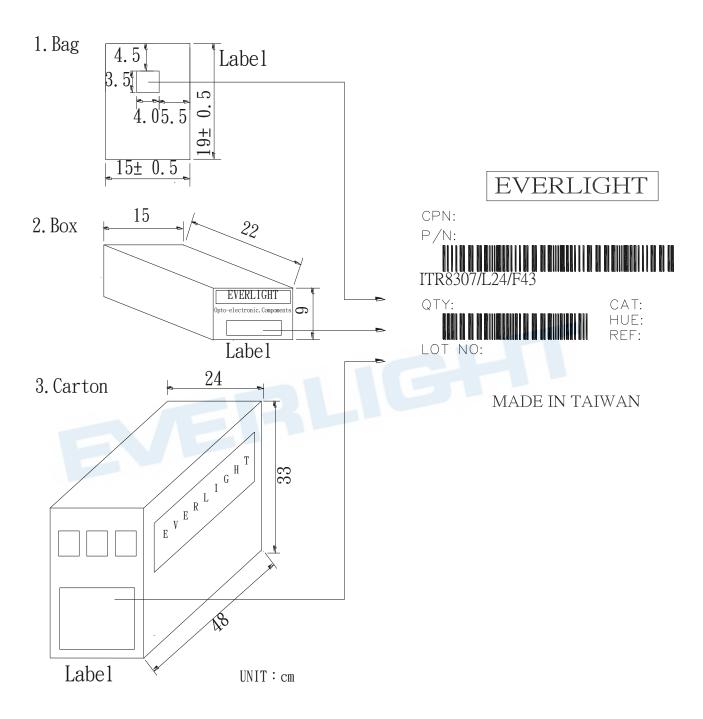
Fig.9 Response Time vs. Load Resistance





Response time (µ s)

Packing Specification



DATASHEET ITR8307/L24



Packing Quantity

- 1. 1000Pcs/1Bag
- 2. 1Bag/1Carton

Recommended Method of Storage

- The following are general recommendations for moisture sensitive level (MSL) 4 storage and use:
- Shelf life in sealed bag: 12 months at < 40 °C and < 90% relative humidity (RH)
- After bag is opened, devices that will be subjected to reflow solder or other high temperature process must a) Mounted within 72 hours of factory conditions < 30 °C/60% RH, or
 - b) Stored at <20% RH
- Devices require bake, before mounting, if:
 Humidity Indicator Card is > 20% when read at 23 ± 5 °C
- If baking is required, devices may be baked:
 - a) 192 hours at 40°C, and <5% RH(dry air/nitrogen) or
 - b) 96 hours at 60°C, and <5% RH for all device containers
 - c) 24 hours at 125 °C

DISCLAIMER

- 1.EVERLIGHT reserves the right(s) on the adjustment of product material mix for the specification.
- 2.The product meets EVERLIGHT published specification for a period of twelve (12) months from date of shipment.
- 3. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
- 4. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from the use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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